Voltage Variable RF Attenuator

50 to 6000 MHz

GENERAL DESCRIPTION

The F2258 is a low insertion loss **V**oltage **V**ariable RF **A**ttenuator (VVA) designed for a multitude of wireless and other RF applications. This device covers a broad frequency range from 50 MHz to 6000 MHz. In addition to providing low insertion loss, the F2258 provides excellent linearity performance over its entire voltage control and attenuation range.

The F2258 uses a single positive supply voltage of 3.15 V to 5.25 V. Another feature includes multi-directional operation meaning the RF input can be applied to either RF1 or RF2 pins. Control voltage ranges from 0 V to 3.6 V.

COMPETITIVE ADVANTAGE

F2258 provides extremely low insertion loss and superb IP3, IP2, Return Loss and Slope Linearity across the control range. Comparing to the previous state-of-the-art for silicon VVAs this device is better as follows:

- ✓ Insertion Loss:
  @ 2000 MHz: 1.4 dB vs. 2.8 dB
  @ 6000 MHz: 2.7 dB vs. 7.0 dB

- ✓ Maximum Attenuation Slope:
  33 dB/Volt vs. 53 dB/Volt

- ✓ Minimum Return Loss up to 6000 MHz:
  12.5 dB vs. 7 dB

- ✓ Minimum Output IP3:
  31 dBm vs. 15 dBm

- ✓ Minimum Input IP2:
  87 dBm vs. 80 dBm

- ✓ Maximum Operating Temperature:
  +105 °C vs. +85 °C

APPLICATIONS

- Base Station 2G, 3G, 4G,
- Portable Wireless
- Repeaters and E911 systems
- Digital Pre-Distortion
- Point to Point Infrastructure
- Public Safety Infrastructure
- Satellite Receivers and Modems
- WIMAX Receivers and Transmitters
- Military Systems, JTRS radios
- RFID handheld and portable readers
- Cable Infrastructure
- Wireless LAN
- Test / ATE Equipment

FEATURES

- Low Insertion Loss: 1.4 dB @ 2000 MHz
- Typical / Min IIP3: 65 dBm / 47 dBm
- Typical / Min IIP2: 95 dBm / 87 dBm
- 33.6 dB Attenuation Range
- Bi-directional RF ports
- +34.4 dBm Input P1dB compression
- Linear-in-dB attenuation characteristic
- Supply voltage: 3.15 V to 5.25 V
- V_{CTRL} range: 0 V to 3.6 V using 5 V supply
- +105 °C max operating temperature
- 3 mm x 3 mm, 16-pin QFN package

FUNCTIONAL BLOCK DIAGRAM
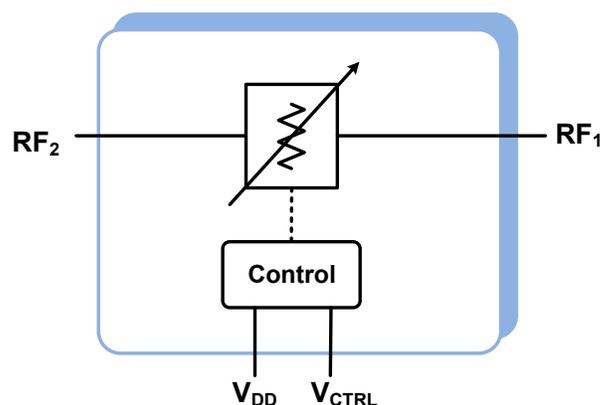
ORDERING INFORMATION

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Min	Max	Units
V_{DD} to GND	V_{DD}	-0.3	+5.5	V
V_{CTRL} to GND (with 0 V $\leq V_{DD} \leq$ 5.25 V)	V_{CTRL}	-0.3	Minimum ($V_{DD,}$ +4.0)	V
RF1, RF2 to GND	V_{RF}	-0.3	0.3	V
RF1 or RF2 Input Power applied for 24 hours maximum (V_{DD} applied @ 2000 MHz and T_{case}=+85°C)	P_{MAX24}		30	dBm
Junction Temperature	T_j		150	°C
Storage Temperature Range	T_{st}	-65	150	°C
Lead Temperature (soldering, 10s)			260	°C
ElectroStatic Discharge – HBM (JEDEC/ESDA JS-001-2012)	V_{ESDHBM}		(Class 1C)	
ElectroStatic Discharge – CDM (JEDEC 22-C101F)	V_{ESDCDM}		(Class C3)	

Stresses above those listed above may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

PACKAGE THERMAL AND MOISTURE CHARACTERISTICS

θ$_{JA}$ (Junction – Ambient)   80.6 °C/W

θ$_{JC}$ (Junction – Case) [The Case is defined as the exposed paddle]   5.1 °C/W

Moisture Sensitivity Rating (Per J-STD-020)   MSL1

F2258 RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Supply Voltage	V_{DD}		3.15		5.25	V
Control Voltage	V_{CTRL}	V_{DD} = 3.90 V to 5.25 V	0		3.6	V
		V_{DD} = 3.15 V to 3.90 V	0		V_{DD}-0.3	
Operating Temperature Range	T_{CASE}	Exposed Paddle	-40		+105	°C
Frequency Range	F_{RF}		50		6000	MHz
RF Operating Power	$P_{MAX, CW}$	Power can be applied to RF1 or RF2			See Figure 1	dBm
RF1 Port Impedance	Z_{RF1}	Single Ended		50		Ω
RF2 Port Impedance	Z_{RF2}	Single Ended		50		Ω
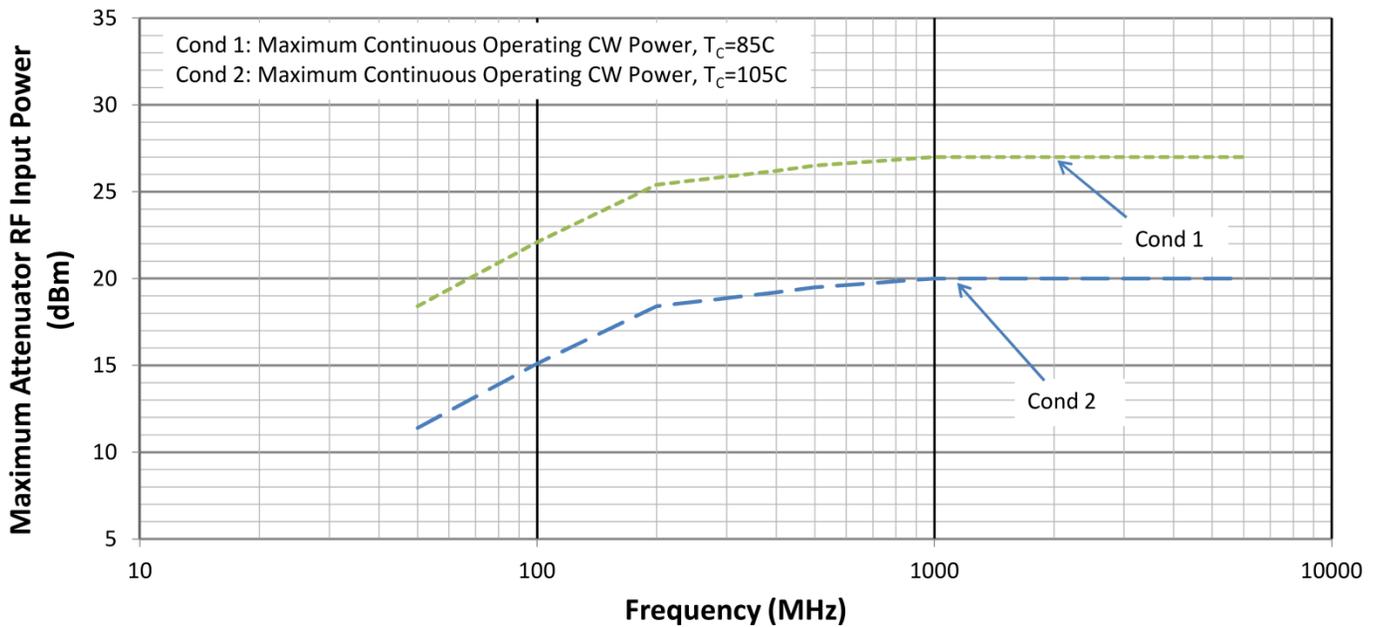
Figure 1 - MAXIMUM RF INPUT POWER VS. RF FREQUENCY

F2258 SPECIFICATION

Refer to EVKit / Applications Circuit, V_{DD} = +3.3 V, T_{CASE} = +25 °C, signal applied to RF1 input, F_{RF} = 2000 MHz, minimum attenuation, P_{IN} = 0 dBm for small signal parameters, +20 dBm for single tone linearity tests, +20 dBm per tone for two tone tests, two tone delta frequency = 50 MHz, PCB board traces and connector losses are de-embedded unless otherwise noted. Refer to Typical Operating Curves for performance over entire frequency band.

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Supply Current	I_{DD}		*0.90[1]*	1.17	*1.40*	mA
Control Current	I_{CTRL}		*-1.0*		*10*	µA
Insertion Loss, IL	A_{MIN}	Minimum Attenuation		1.4	*1.9*	dB
Maximum Attenuation	A_{MAX}		34[2]	35		dB
Insertion Phase Δ	$\Phi_{\Delta MAX}$	At 36 dB attenuation relative to Insertion Loss		27		Deg
	$\Phi_{\Delta MID}$	At 18 dB attenuation relative to Insertion Loss		10		
Input 1dB Compression[3]				34.4		dBm
Minimum RF1 Return Loss over control voltage range	S_{11}	50 MHz[4]		16		dB
		700 MHz		17		
		2000 MHz		17		
		6000 MHz		15		
Minimum RF2 Return Loss over control voltage range	S_{22}	50 MHz[4]		16		dB
		700 MHz		15		
		2000 MHz		16		
		6000 MHz		13		
Input IP3	IIP3			65		dBm
	$IIP3_{MIN}$	All attenuation settings	44	55		
Output IP3	$OIP3_{MIN}$	Maximum attenuation		35		dBm
Input IP2	IIP2	P_{IN} + $IM2_{dBc}$, IM2 term is F1+F2		95		dBm
	$IIP2_{MIN}$	All attenuation settings		87		
Input IH2	HD2	P_{IN} + $H2_{dBc}$		90		dBm
Input IH3	HD3	P_{IN} + ($H3_{dBc}$/2)		54		dBm
Settling Time	$T_{SETTL0.1dB}$	Any 1 dB step in the 0 dB to 33 dB control range 50% V_{CTRL} to RF settled to within ± 0.1 dB		15		µs

Note 1: Items in min/max columns in **bold italics** are Guaranteed by Test.
Note 2: Items in min/max columns that are not bold/italics are Guaranteed by Design Characterization.
Note 3: The input 1dB compression point is a linearity figure of merit. Refer to Absolute Maximum Ratings section along with Figure 1 for the maximum RF input power vs. RF frequency
Note 4: Set blocking capacitors C1 & C2 to 0.01uF to achieve best return loss performance at 50 MHz.

TYPICAL OPERATING CONDITIONS (TOC)

Unless otherwise noted for the TOC graphs on the following pages, the following conditions apply.

- V_{DD} = +3.3 V or +5.0 V
- T_{CASE} = +25 ºC
- F_{RF} = 2000 MHz
- **RF trace and connector losses are de-embedded for S-parameters**
- **Pin = 0 dBm for all small signal tests**
- **Pin = +20 dBm for single tone linearity tests (RF1 port driven)**
- **Pin = +20 dBm/tone for two tone linearity tests (RF1 port driven)**
- **Two tone frequency spacing = 50 MHz**

TYPICAL OPERATING CONDITIONS [BROADBAND PERFORMANCE] (- 1 -)

Attenuation vs. V_{CTRL}
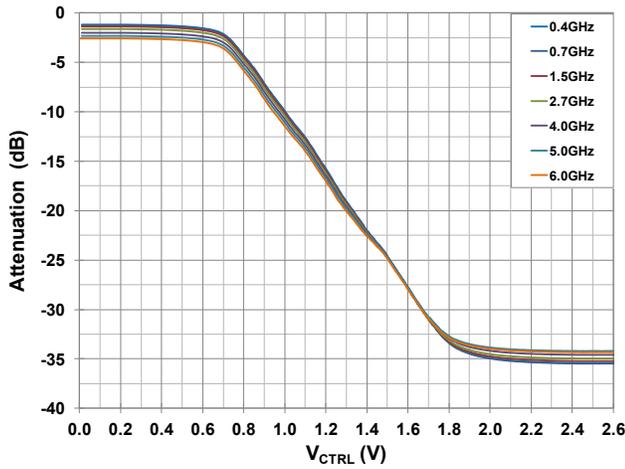
Attenuation vs. Frequency
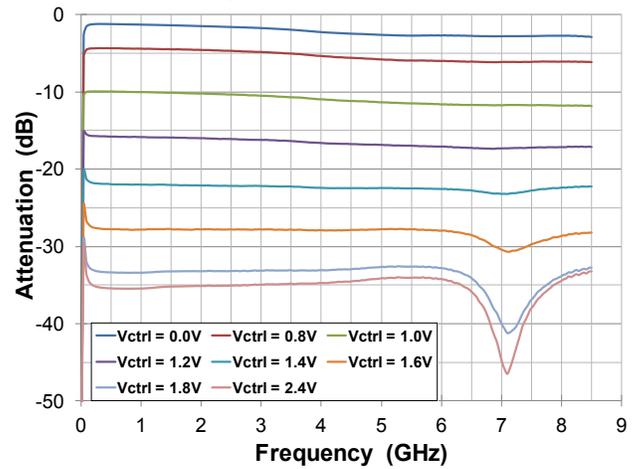
Min. & Max. Attenuation vs. Frequency
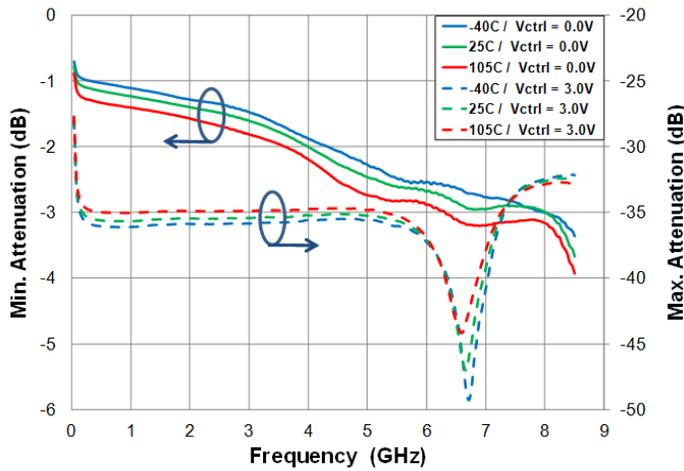
Attenuation Delta to 25C vs. Frequency
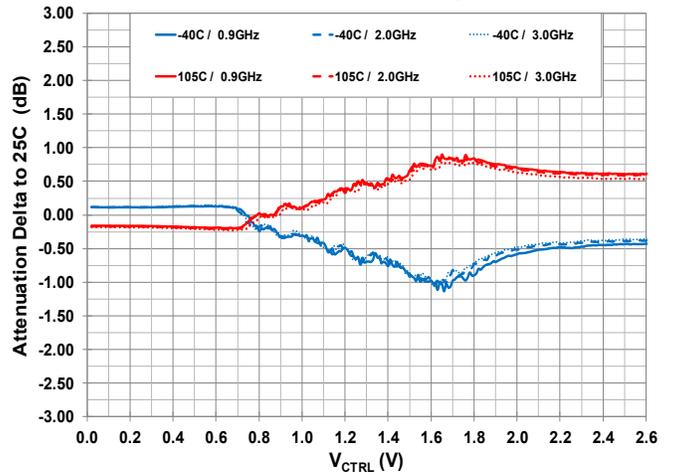
TYPICAL OPERATING CONDITIONS (- 2 -)

Attenuation vs. V$_{CTRL}$
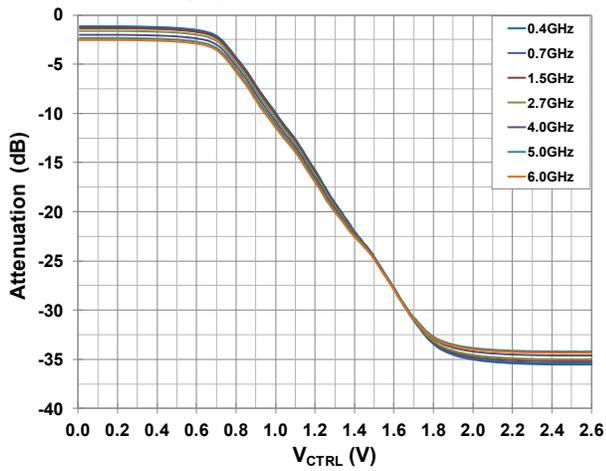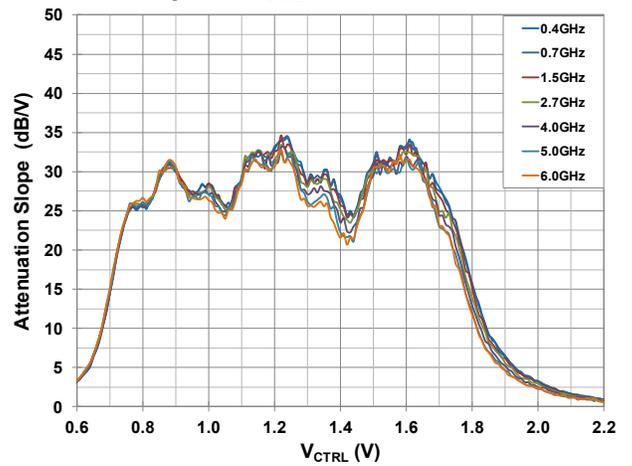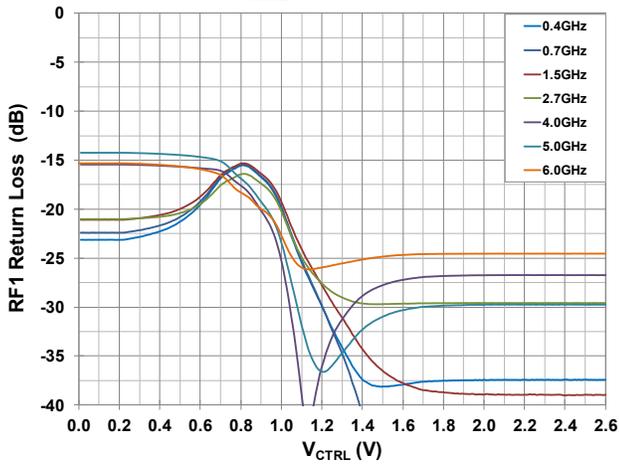
Attenuation Slope vs. V$_{CTRL}$

RF1 Return Loss vs. V$_{CTRL}$

RF2 Return Loss vs. V$_{CTRL}$
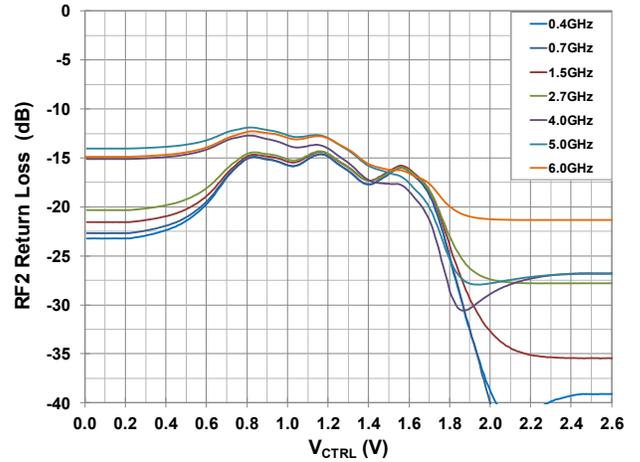
Insertion Phase Δ vs. V$_{CTRL}$
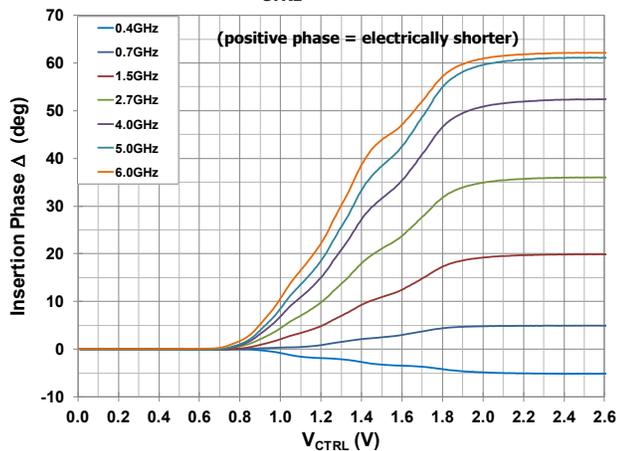
Insertion Phase Slope vs. V$_{CTRL}$
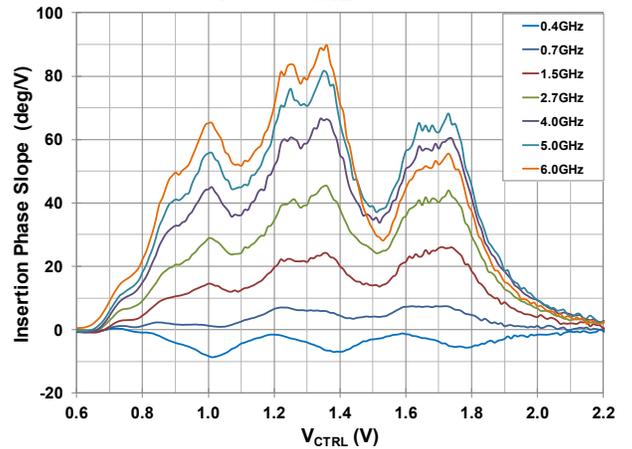
TYPICAL OPERATING CONDITIONS (- 3 -)

Attenuation Response vs. V_CTRL
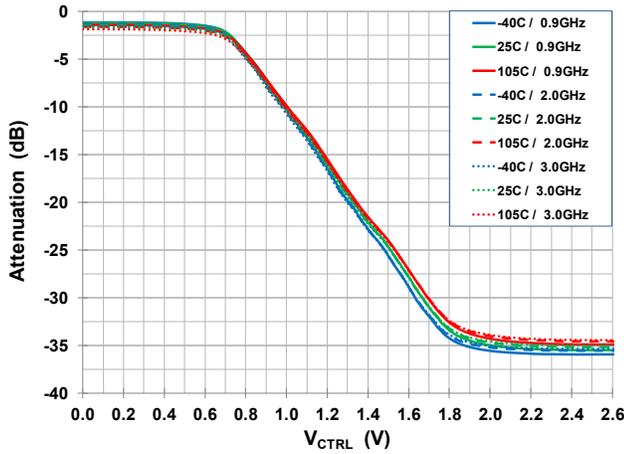
Attenuation Slope vs. V_CTRL
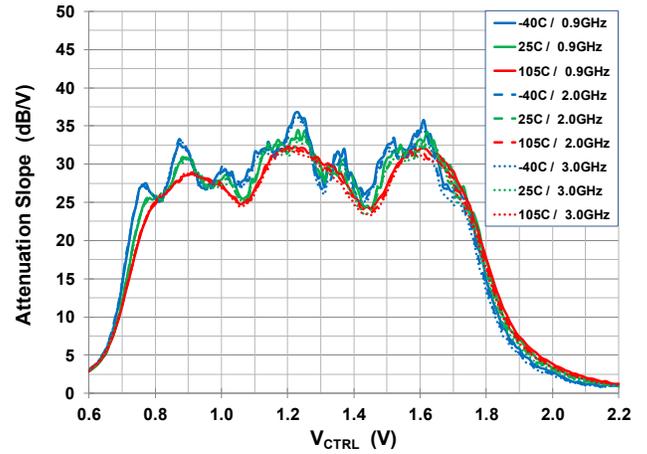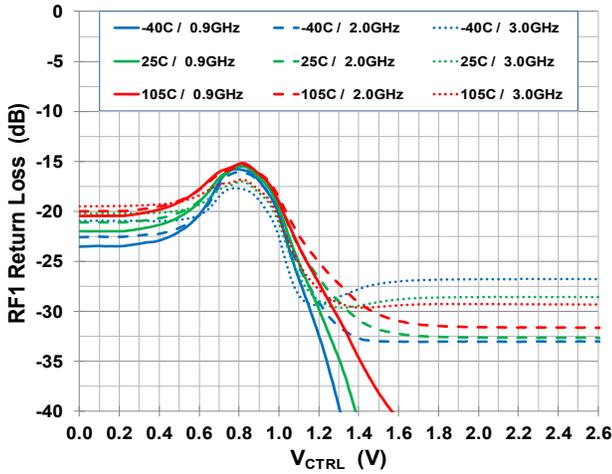
RF1 Return Loss vs. V_CTRL

RF2 Return Loss vs. V_CTRL
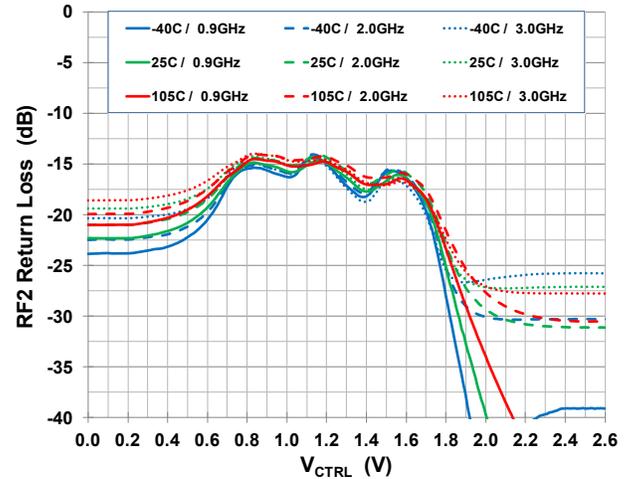
Insertion Phase Δ vs. V_CTRL
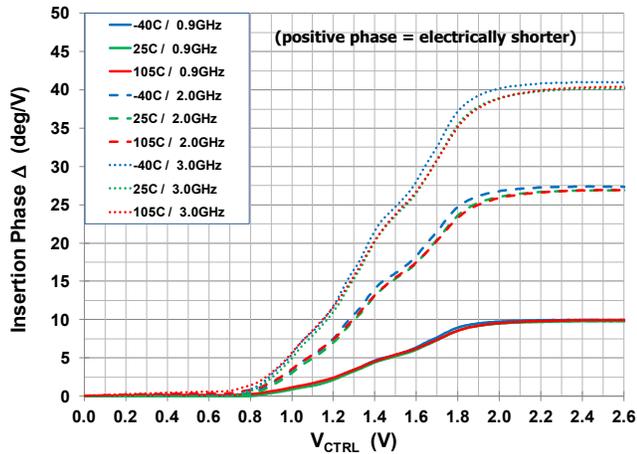
Insertion Phase Slope vs. V_CTRL
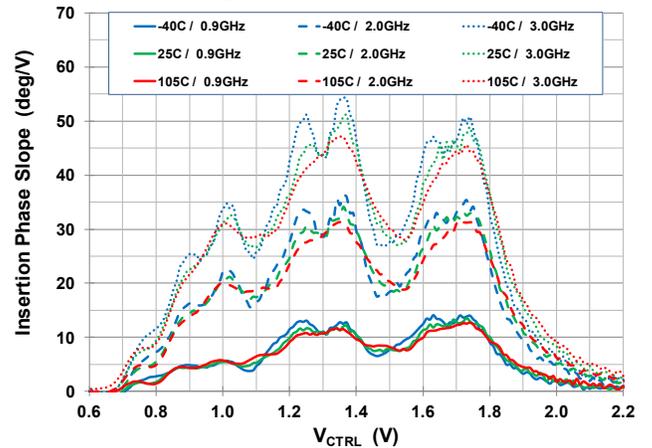
TYPICAL OPERATING CONDITIONS (- 4 -)

RF1 Return Loss vs. Attenuation
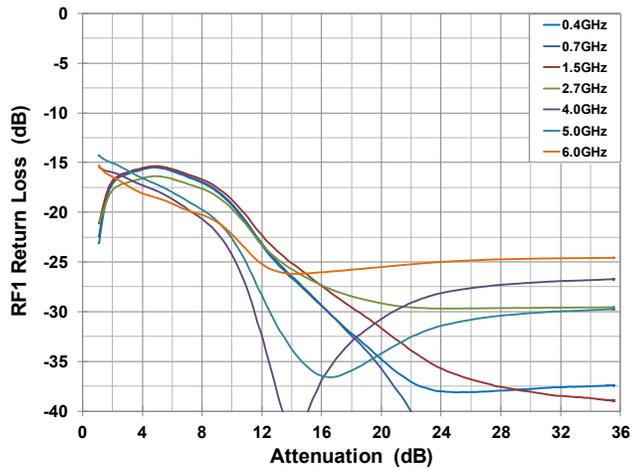
RF1 Return Loss vs. Attenuation
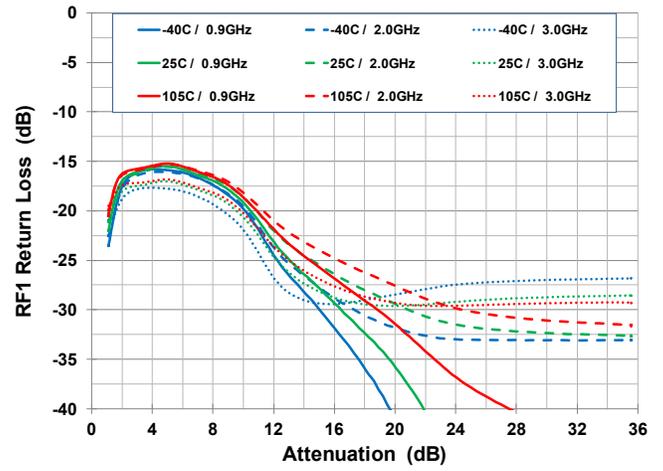
RF2 Return Loss vs. Attenuation
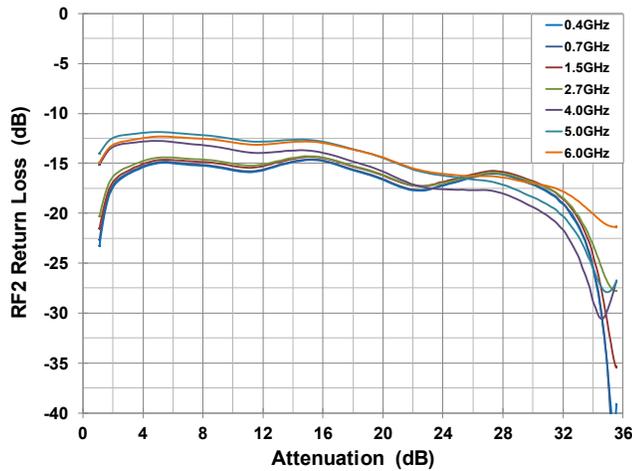
RF2 Return Loss vs. Attenuation
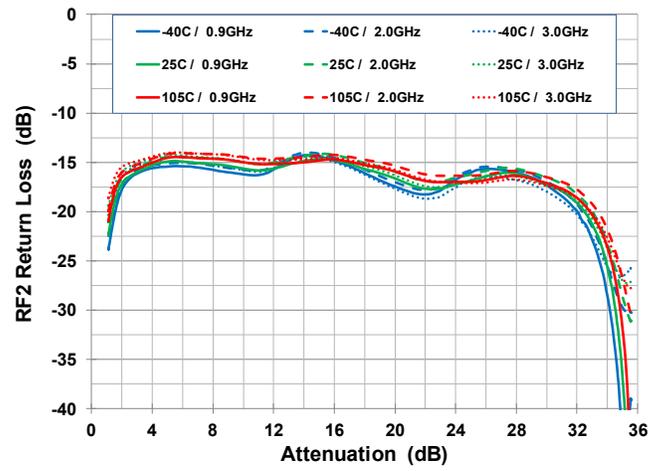
Insertion Phase Δ vs. Attenuation
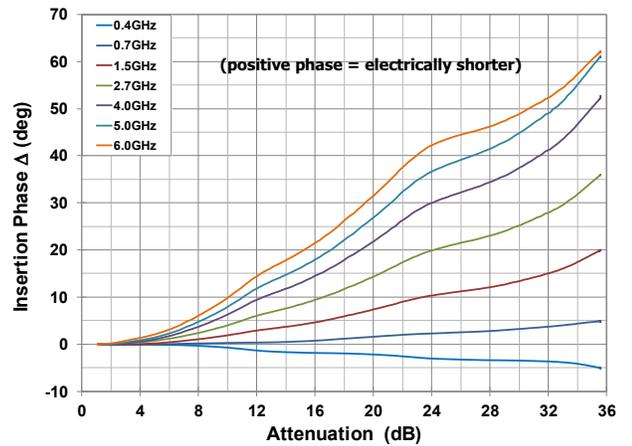
Insertion Phase Δ vs. Attenuation
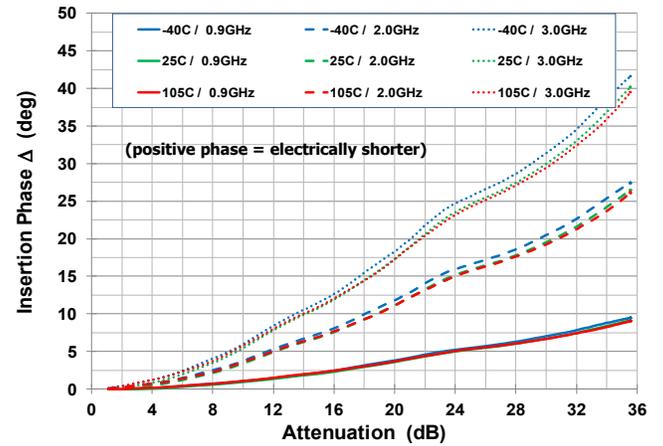
TYPICAL OPERATING CONDITIONS (- 5 -)

Min & Max. Attenuation vs. Frequency
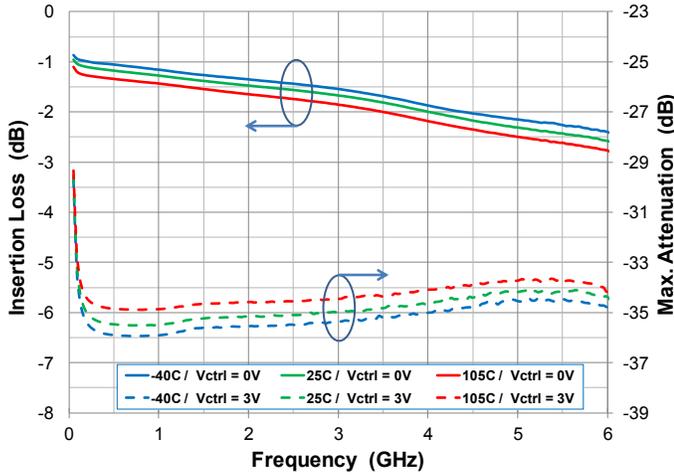
Min. & Max. Attenuation Slope vs. Frequency

VCTRL varied from 0.8V to 1.8V
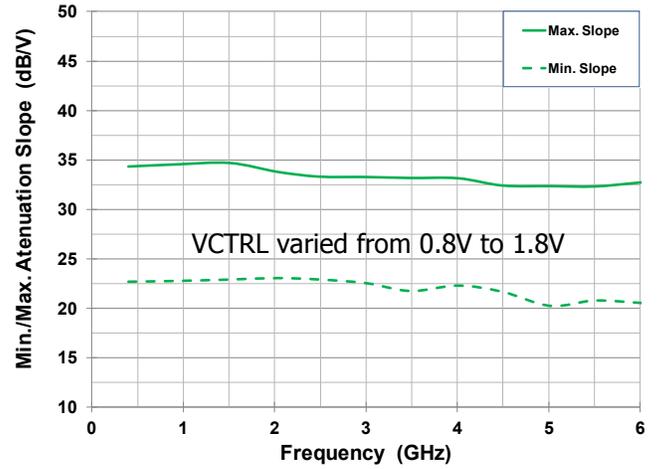
Worst-Case RF1 Return Loss vs. Frequency
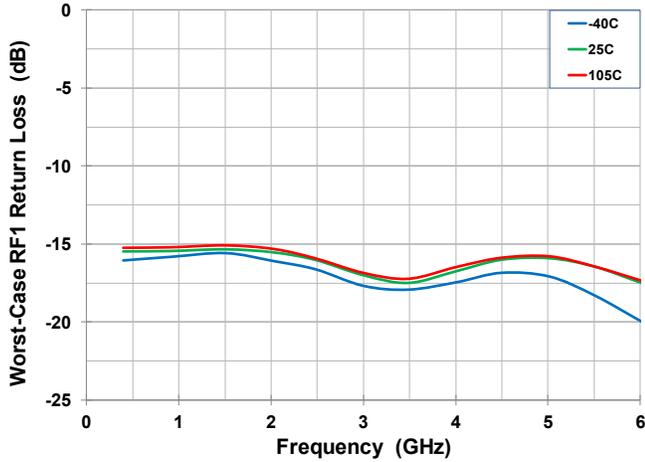
Worst-Case RF2 Return Loss vs. Frequency
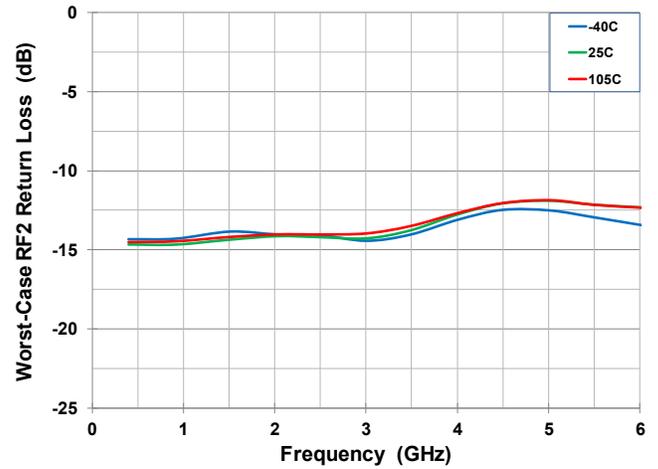
Max. Insertion Phase Δ vs. Frequency

(positive phase = electrically shorter)
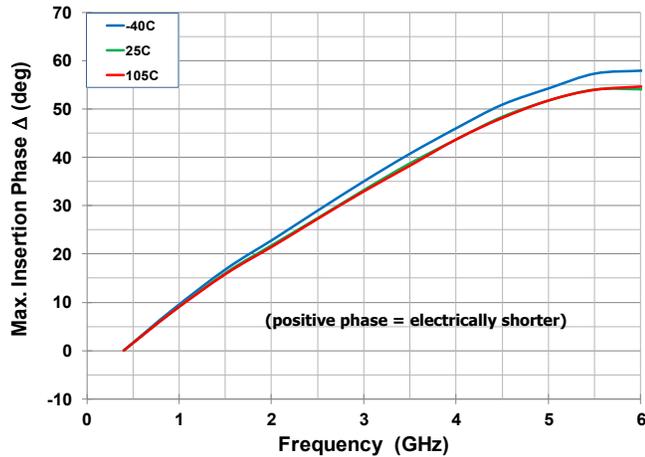
Gain Compression vs. Frequency
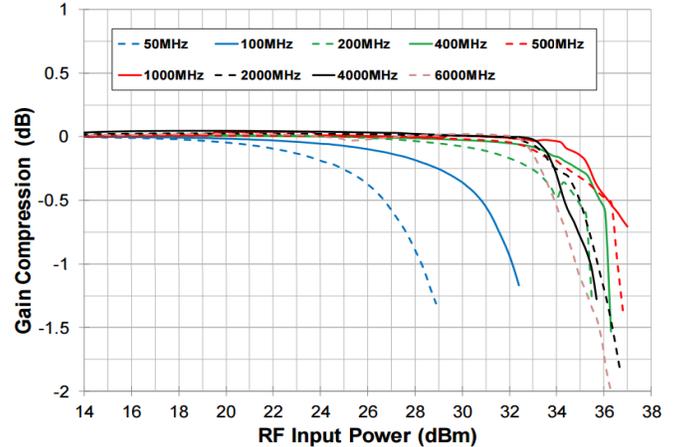
TYPICAL OPERATING CONDITIONS (- 6 -)

Min & Max. Attenuation vs. Low Frequency
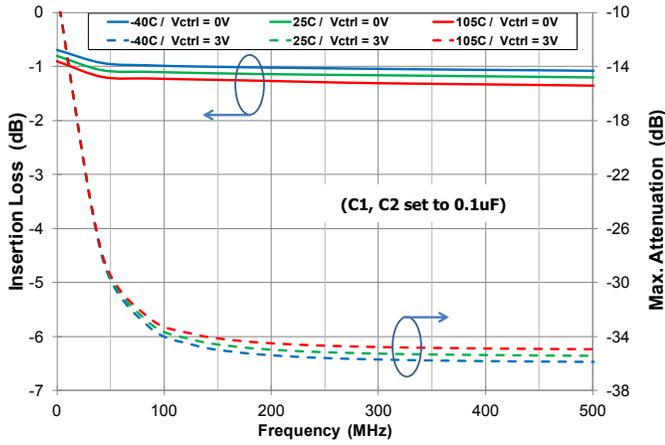
Low-Frequency Attenuation vs. V_CTRL
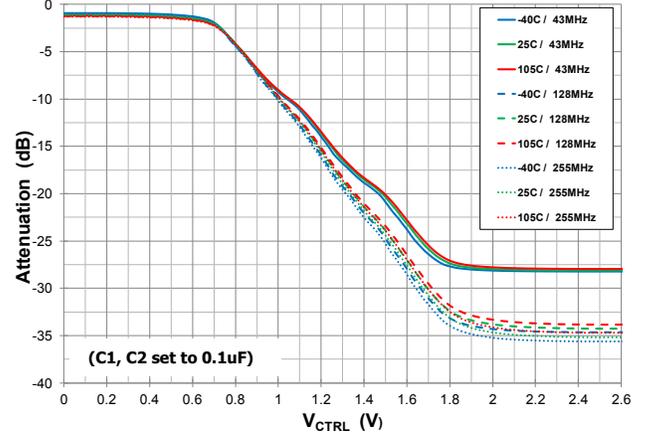
Low-Frequency RF1 Return Loss vs. V_CTRL
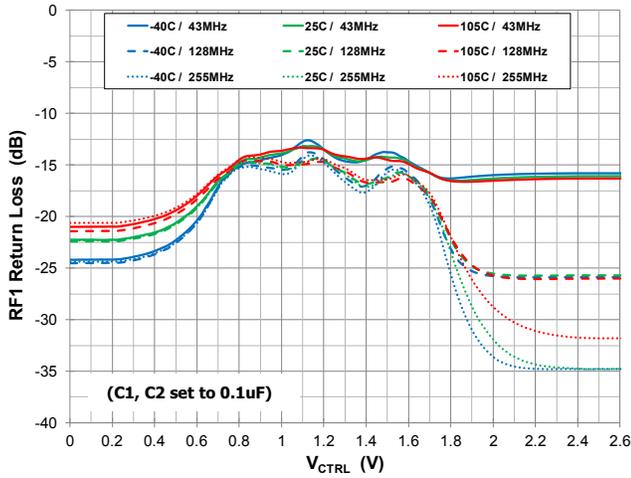
Low-Frequency RF2 Return Loss vs. V_CTRL
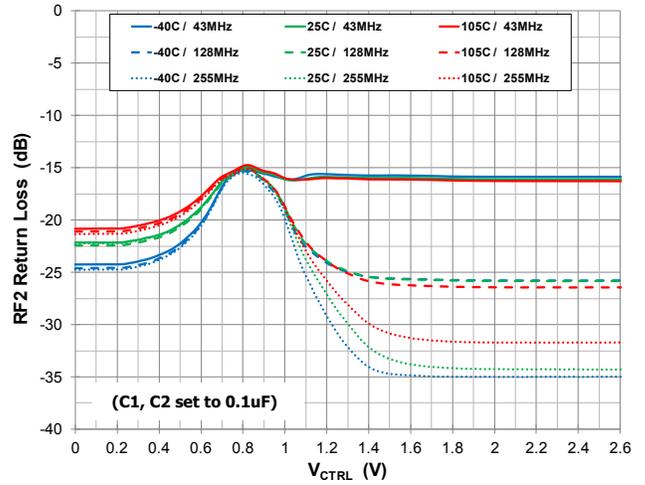
Worst-Case Return Loss vs. Low Frequency
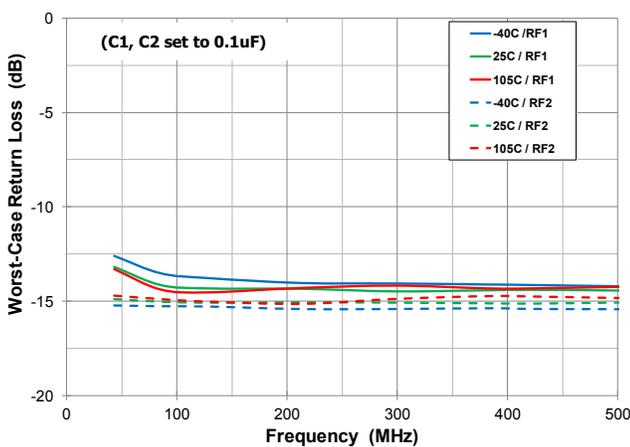
Group Delay vs. V_CTRL
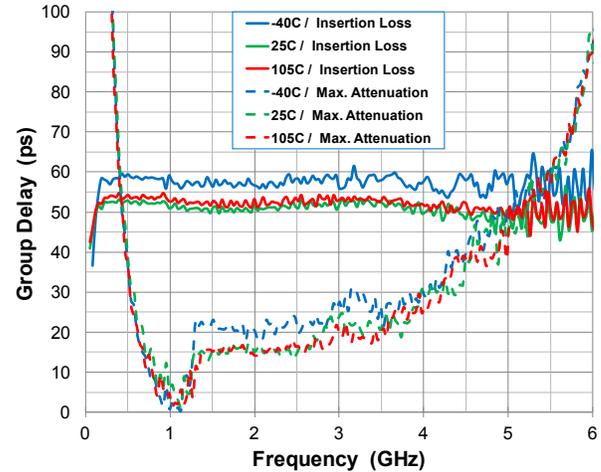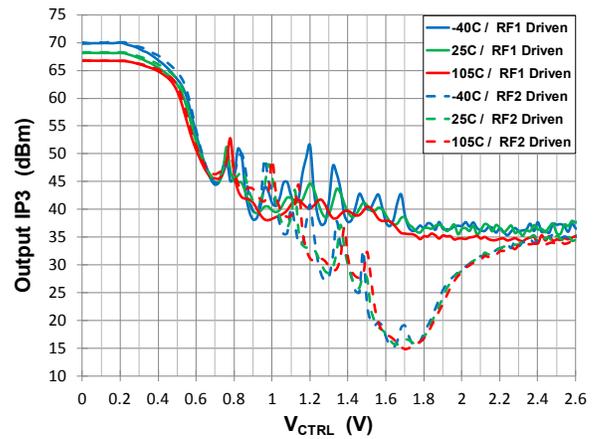
TYPICAL OPERATING CONDITIONS (- 7 -)

Input IP3 vs. V_CTRL
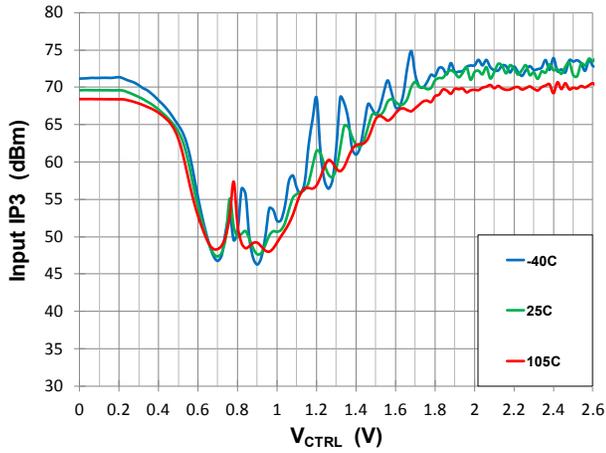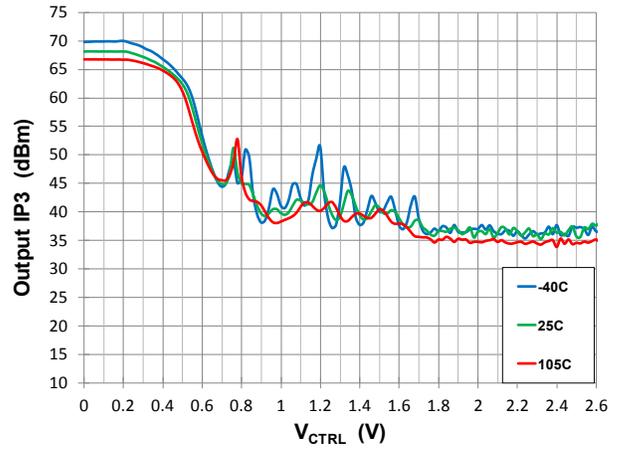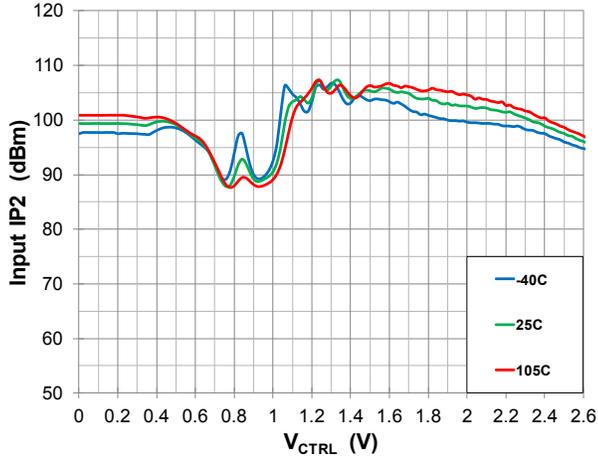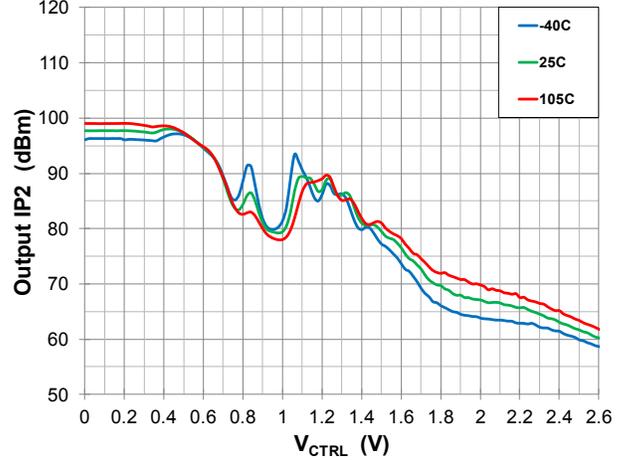
Output IP3 vs. V_CTRL

Input IP2 vs. V_CTRL

Output IP2 vs. V_CTRL

2nd Harm Input Intercept Point vs. V_CTRL
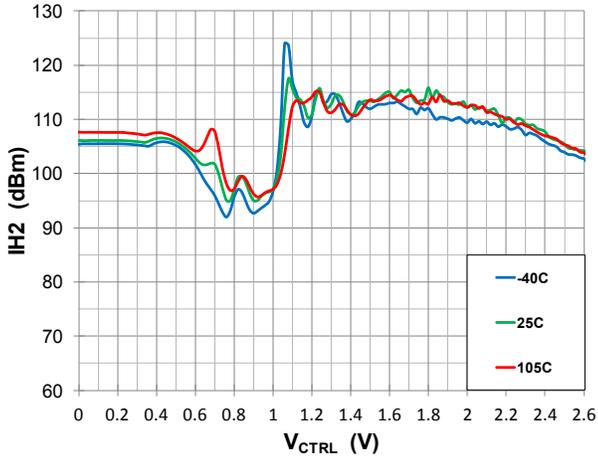
3rd Harm Input Intercept Point vs. V_CTRL
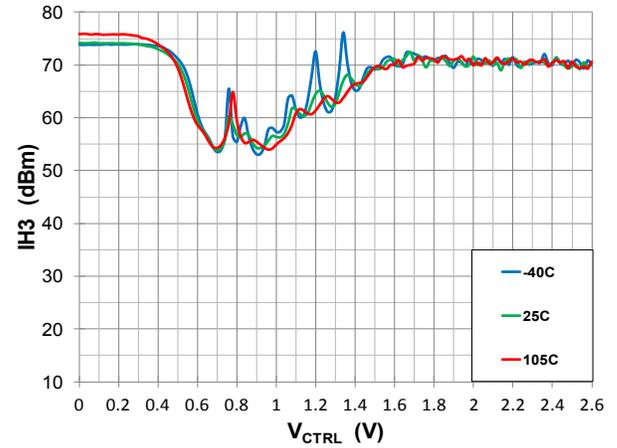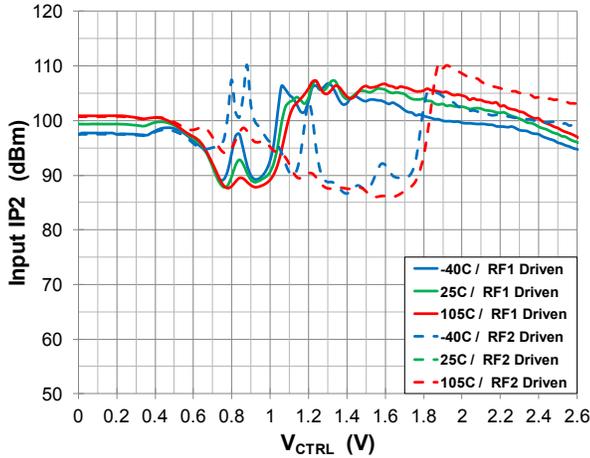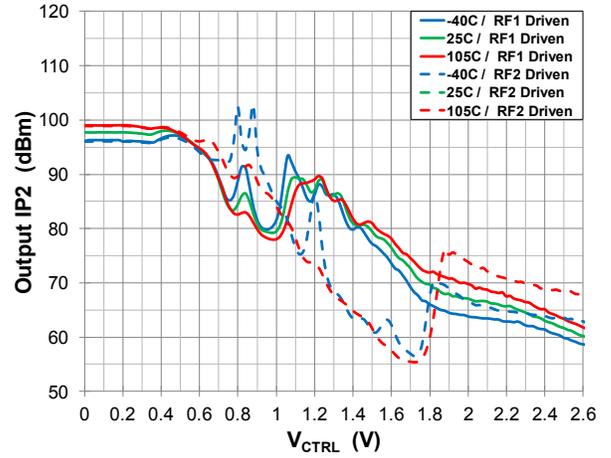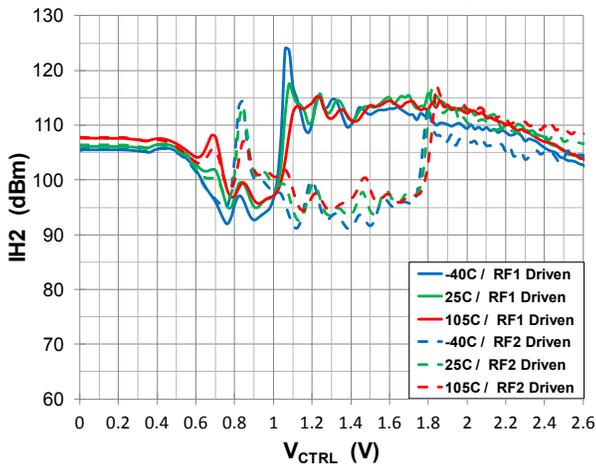
TYPICAL OPERATING CONDITIONS (- 8 -)

Input IP3 vs. V_CTRL
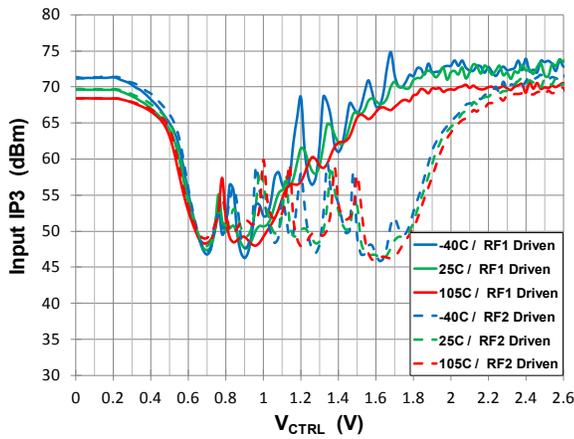
Output IP3 vs. V_CTRL

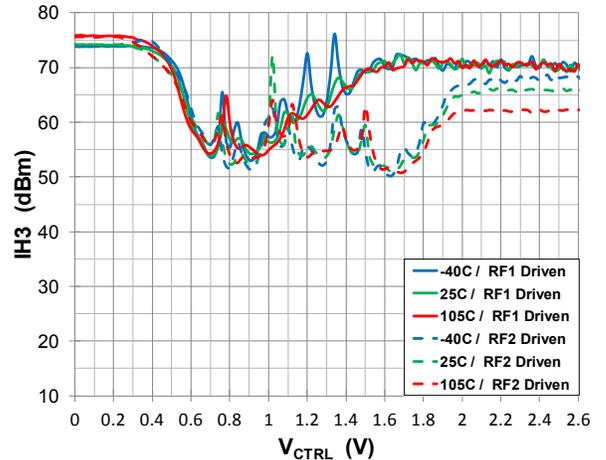**Input IP2 vs. V_CTRL**

Output IP2 vs. V_CTRL

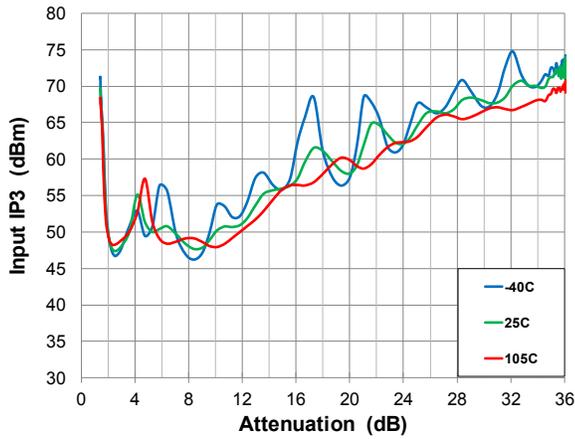**2nd Harm Input Intercept Point vs. V_CTRL**
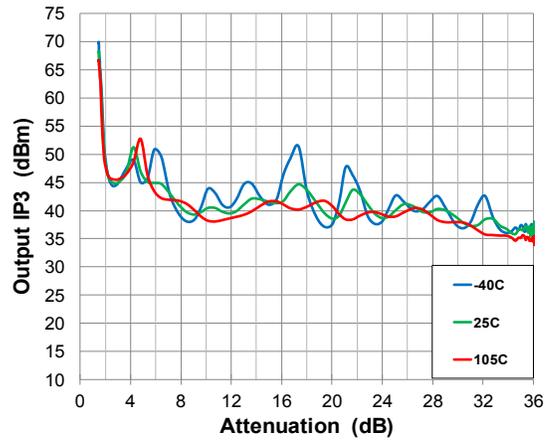

3rd Harm Input Intercept Point vs. V_CTRL
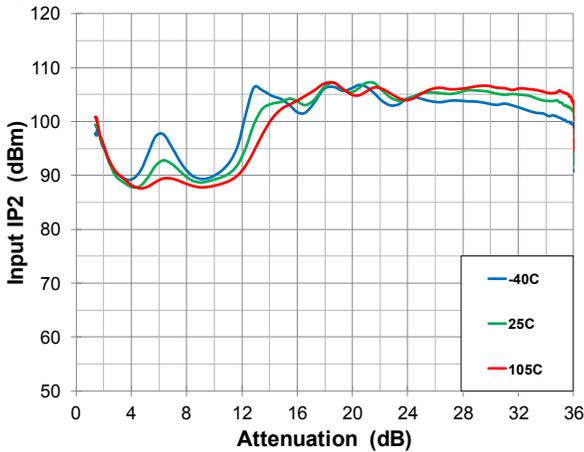
TYPICAL OPERATING CONDITIONS (- 9 -)

Input IP3 vs. Attenuation

Output IP3 vs. Attenuation

Input IP2 vs. Attenuation

Output IP2 vs. Attenuation

2nd Harm Input Intercept Point vs. Attenuation

3rd Harm Input Intercept Point vs. Attenuation

TYPICAL OPERATING CONDITIONS (- 10 -)
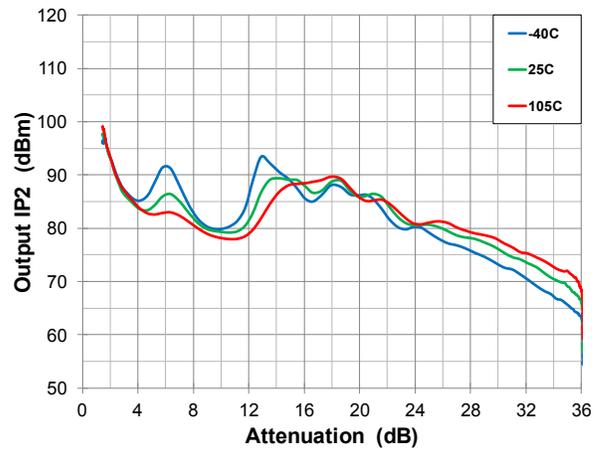
Input IP3 vs. Attenuation

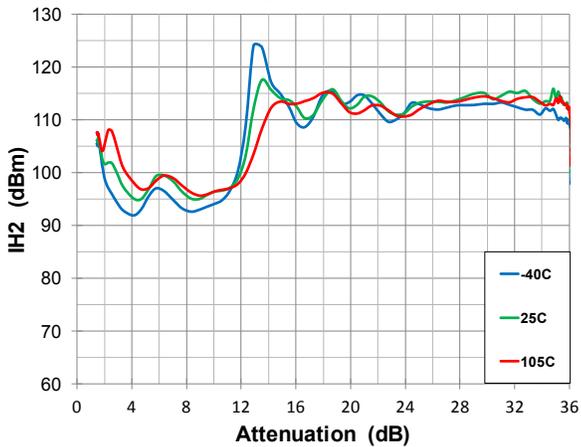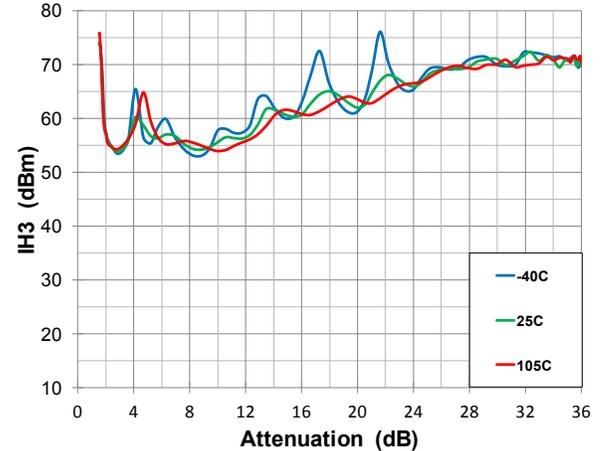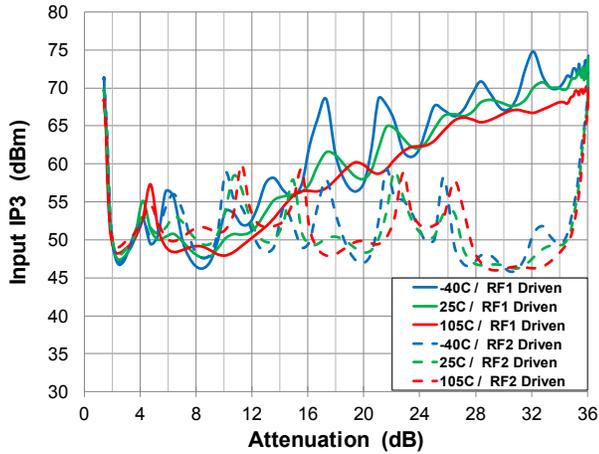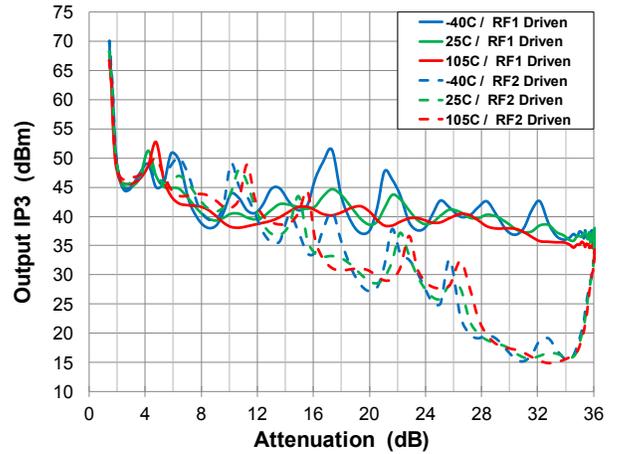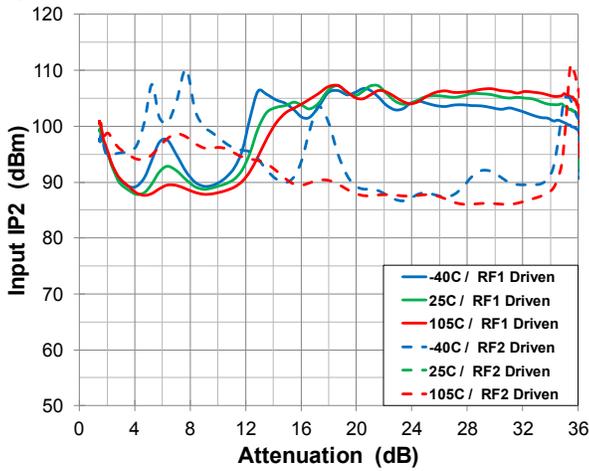**Output IP3 vs. Attenuation**

Input IP2 vs. Attenuation

Output IP2 vs. Attenuation
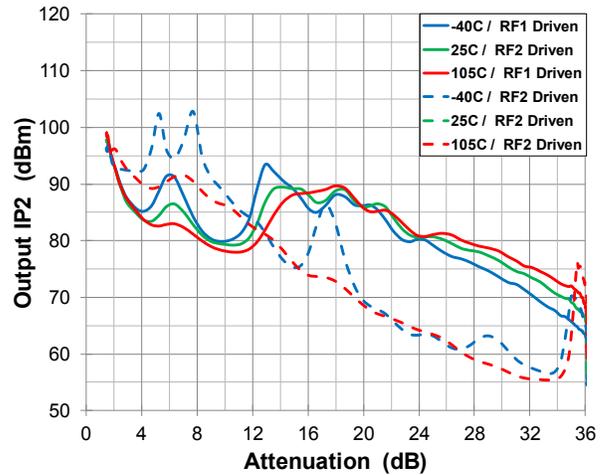
2nd Harm Input Intercept Point vs. Attenuation
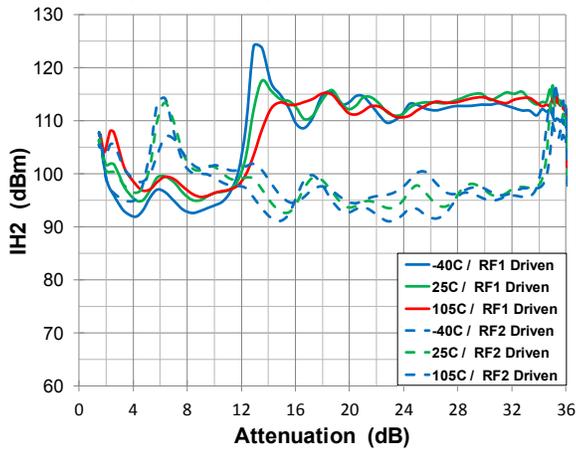
3rd Harm Input Intercept Point vs. Attenuation
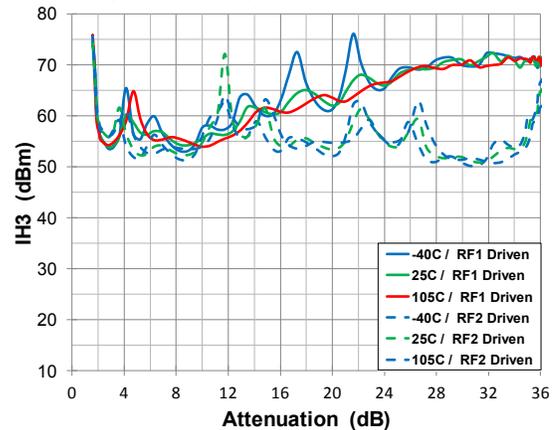
PACKAGE DRAWING

(3mm x 3mm 16-pin TQFN), NLG16
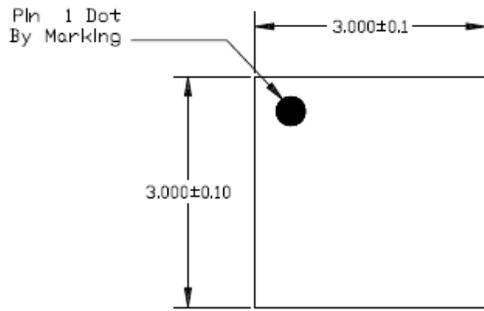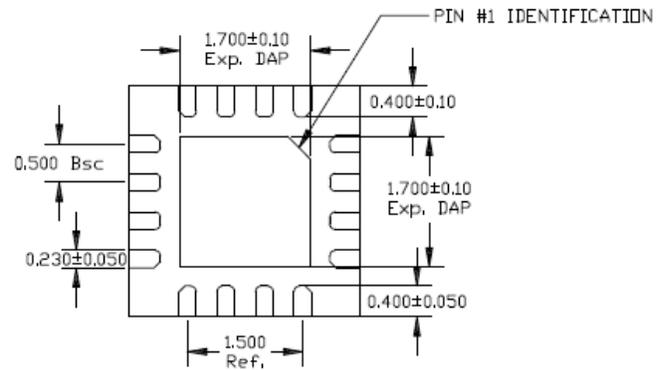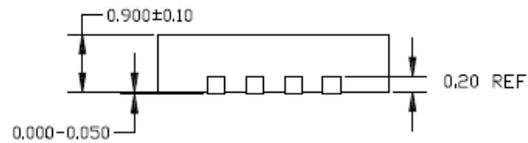
LAND PATTERN DIMENSION
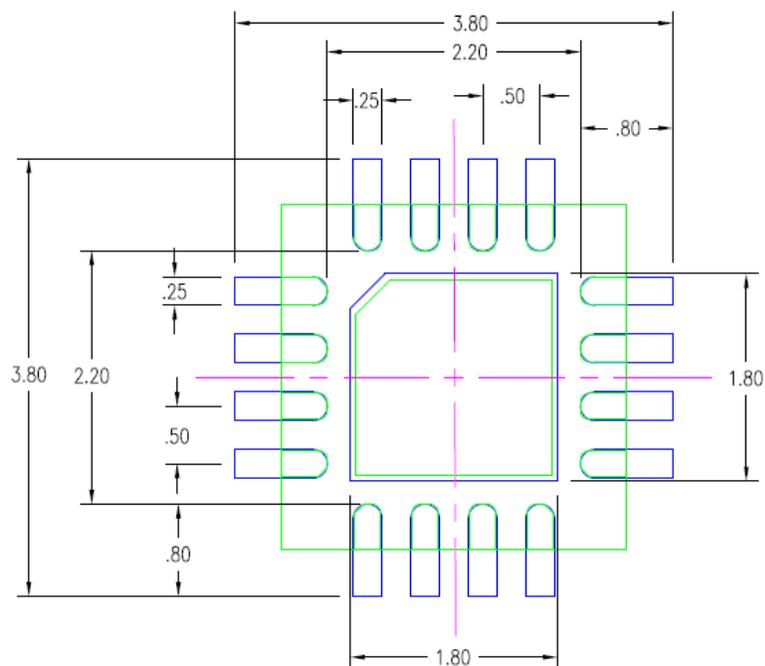
NOTES:
1. ALL DIMENSION ARE IN mm. ANGLES IN DEGREES.
2. TOP DOWN VIEW. AS VIEWED ON PCB.
3. COMPONENT OUTLINE SHOW FOR REFERENCE IN GREEN.
4. LAND PATTERN IN BLUE. NSMD PATTERN ASSUMED.
5. LAND PATTERN RECOMMENDATION PER IPC-7351B GENERIC REQUIREMENT
   FOR SURFACE MOUNT DESIGN AND LAND PATTERN.

PIN DIAGRAM

PIN DESCRIPTION

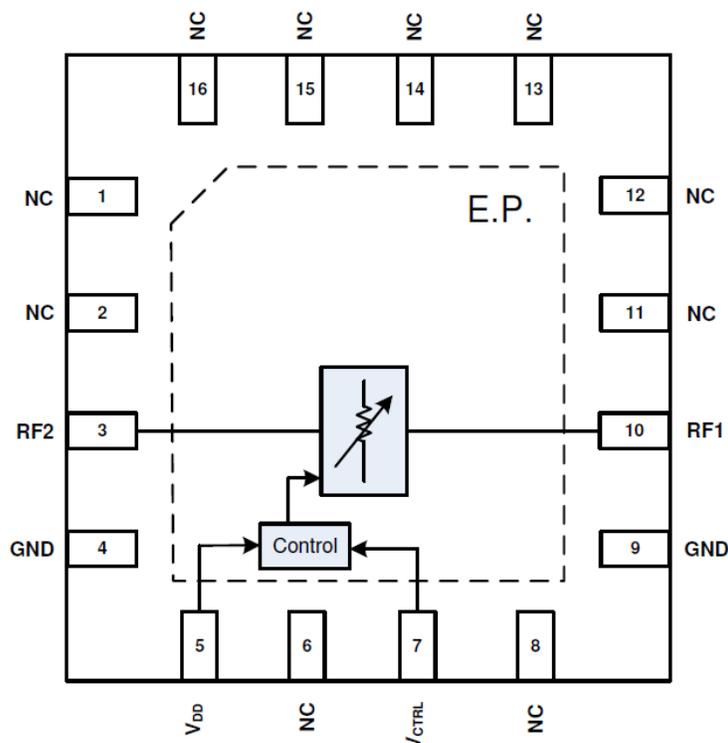| Pin	Name	Function
4, 9	GND	Ground these pins as close to the device as possible.
3	RF2	RF Port 2. Matched to 50 ohms. Must use an external AC coupling capacitor as close to the device as possible. For low frequency operation increase the capacitor value to result in a low reactance at the frequency of interest.
5	V_{DD}	Power supply input. Bypass to GND with capacitors close as possible to pin.
1, 2, 6, 8, 11, 12, 13, 14, 15, 16	NC	No internal connection. These pins can be left unconnected or connected to ground.
7	V_{CTRL}	Attenuator control voltage. Apply a voltage in the range as specified in the Operating Conditions Table. See application section for details about V_{CTRL}.
10	RF1	RF Port 1. Matched to 50 ohms. Must use an external AC coupling capacitor as close to the device as possible. For low frequency operation increase the capacitor value to result in a low reactance at the frequency of interest.
—	EP	Exposed Pad. Internally connected to GND. Solder this exposed pad to a PCB pad that uses multiple ground vias to achieve the specified RF performance.

APPLICATIONS INFORMATION

Default Start-up

The V_{CTRL} pin has an internal pull-down resistor. If left floating, the part will power up in the minimum attenuation state.

VCTRL

The V_{CTRl} pin is used to control the attenuation of the F2258. With V_{DD} = 5 V the control range of V_{CTRl} is from 0 V (minimum attenuation) to 3.6 V (maximum attenuation). For other settings of V_{DD} refer to the Operating Conditions Table. Apply V_{DD} before applying voltage to the V_{CTRl} pin to prevent damage to the on-chip pull-up ESD diode. If this sequencing is not possible, then set resistor R2 to 1kΩ to limit the current into the V_{CTRl} pin.

RF1 and RF2 Ports

The F2258 is a bi-directional device thus allowing RF1 or RF2 to be used as the RF input. As displayed in the Typical Operating Conditions curves, RF1 shows enhanced linearity. V_{DD} must be applied prior to the application of RF power to ensure reliability. DC blocking capacitors are required on the RF pins and should be set to a value that results in a low reactance over the frequency range of interest.

Power Supplies

The supply pin should be bypassed with external capacitors to minimize noise and fast transients. Supply noise can degrade noise figure and fast transients can trigger ESD clamps and cause them to fail. Supply voltage change or transients should have a slew rate smaller than 1V/20uS. In addition, all control pins should remain at 0V (+/-0.3V) while the supply voltage ramps or while it returns to zero.
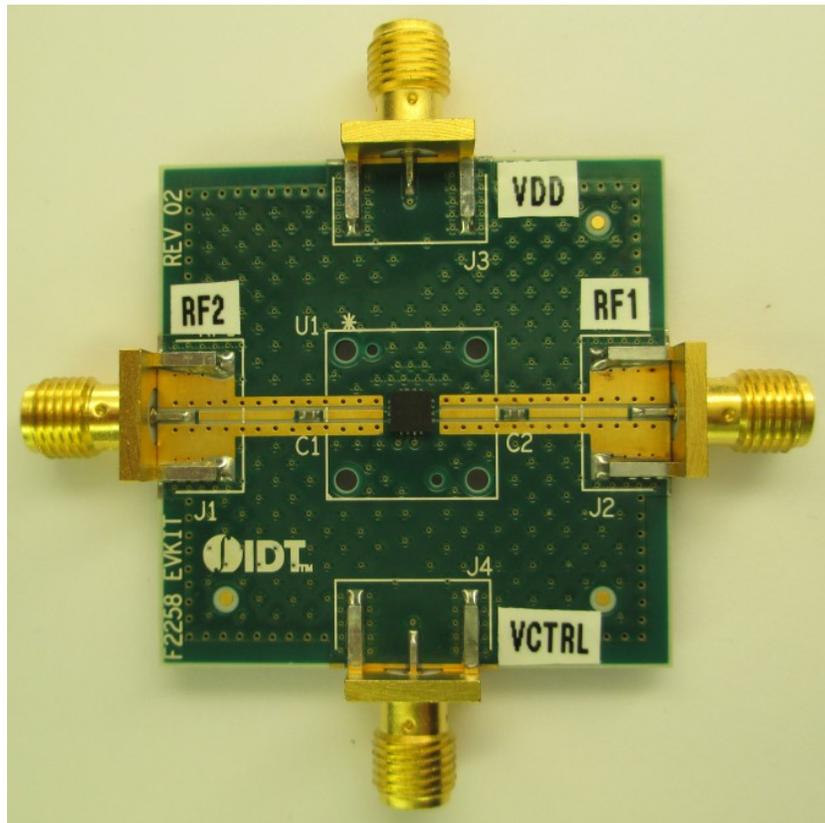
Control Pin Interface

If control signal integrity is a concern and clean signals cannot be guaranteed due to overshoot, undershoot, ringing, etc., the following circuit at the input of control pin 7 is recommended as shown below.
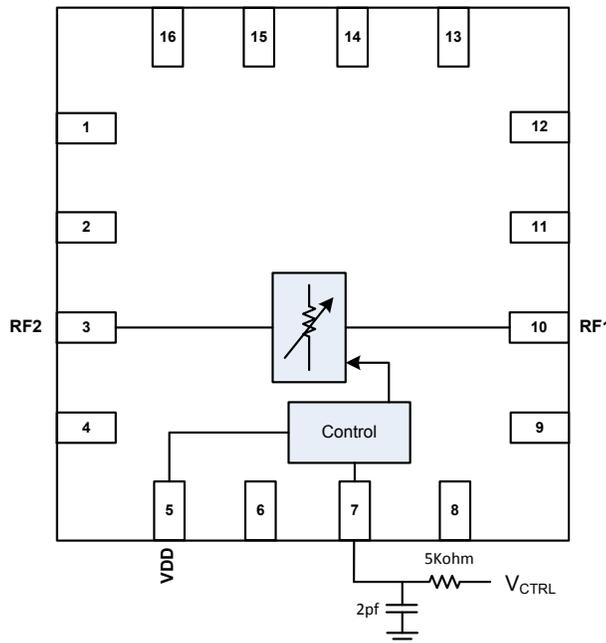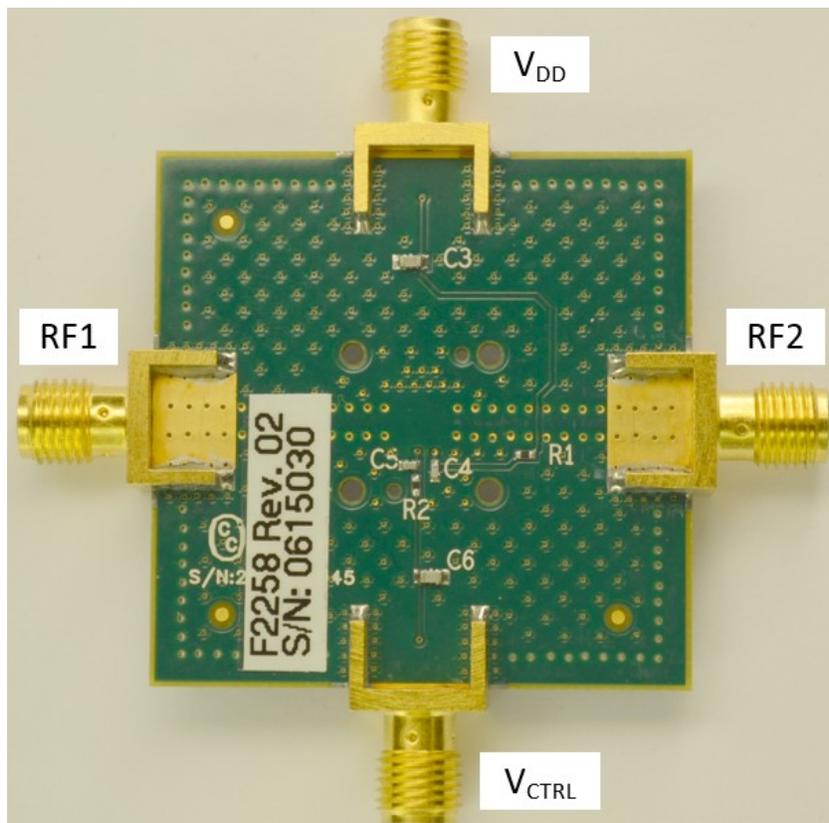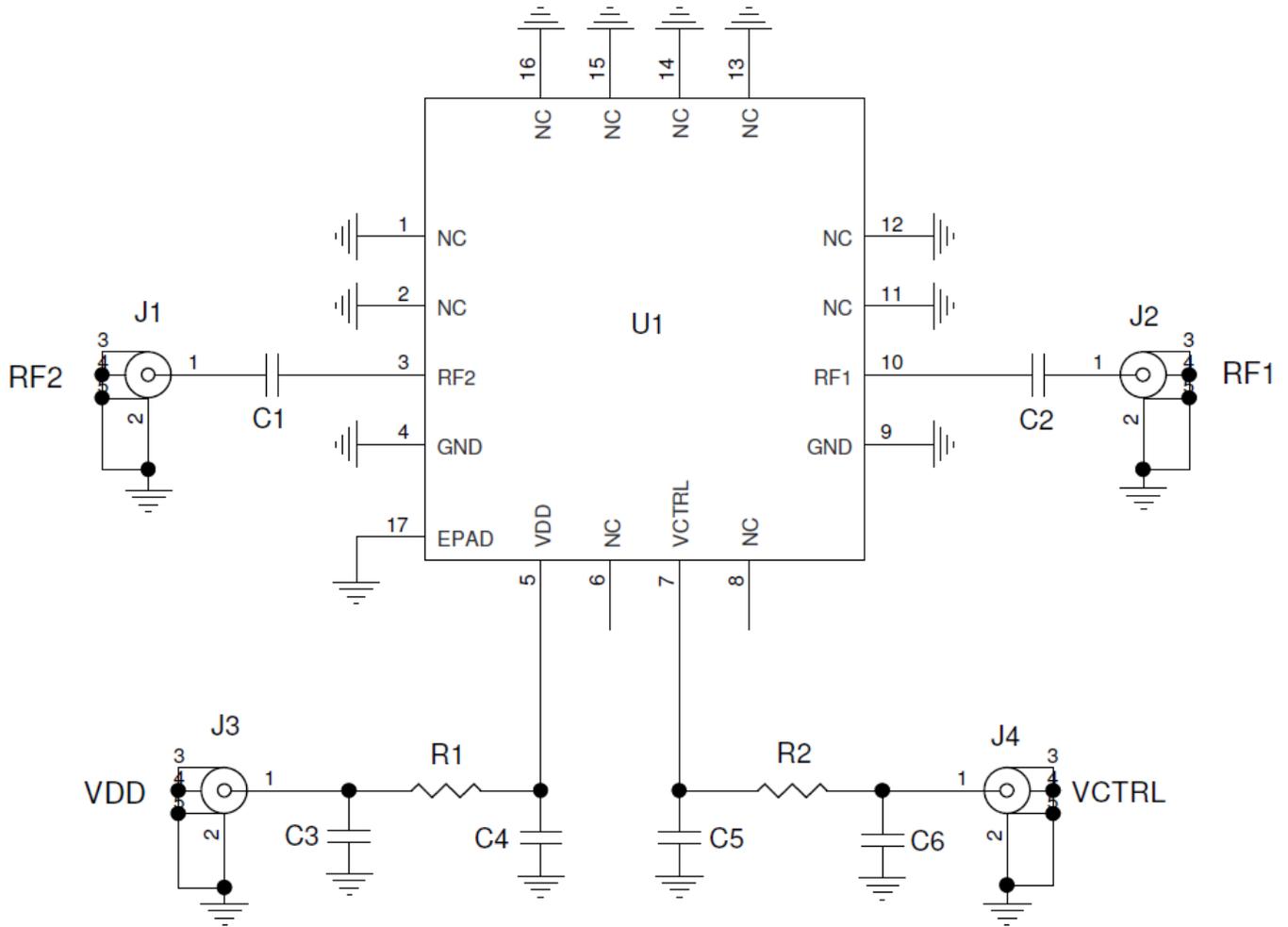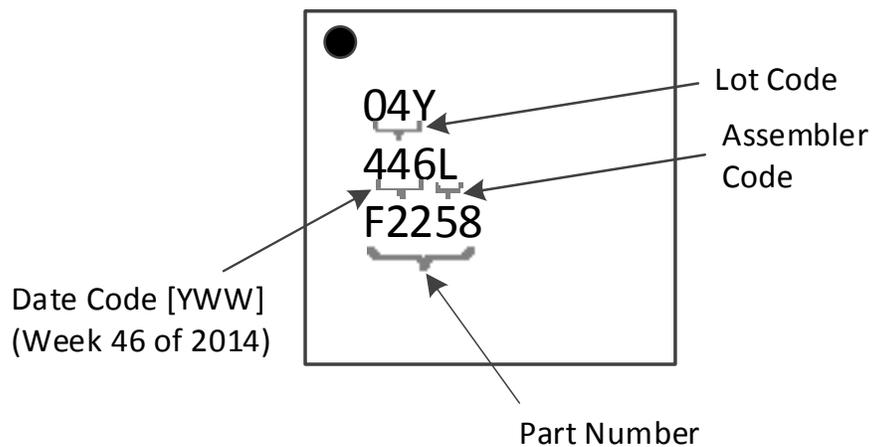
EVKIT PICTURE

Top View

Bottom View

EVKIT / APPLICATIONS CIRCUIT

EVKIT BOM (REV 02)

Item #	Part Reference	QTY	DESCRIPTION	Mfr. Part #	Mfr.
1	C3, C6	2	10nF ±5%, 50V, X7R Ceramic Capacitor (0603)	GRM188R71H103J	Murata
2	C4, C5	2	1000pF ±5%, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1H102J	Murata
3	C1, C2	2	100pF ±5%, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1H101J	Murata
4	R1, R2	2	0Ω Resistors (0402)	ERJ-2GE0R00X	Panasonic
5	J1, J2, J3, J4	4	Edge Launch SMA (0.375 inch pitch ground tabs)	142-0701-851	Emerson Johnson
6	U1	1	Voltage Variable Attenuator	F2258NLGK	IDT
7		1	Printed Circuit Board	F2258 EVKIT REV 02	IDT

TOP MARKINGS

```
 ●
    04Y          ────→ Lot Code

    446L         ────→ Assembler
                        Code
    F2258

Date Code [YWW]
(Week 46 of 2014)

              Part Number
```

REVISION HISTORY SHEET

Rev	Date	Page	Description of Change
O	2015-Aug-03		Initial Release

Corporate Headquarters
6024 Silver Creek Valley Road
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www.idt.com

Tech Support
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 [F2258NLGK8](#) [F2258NLGK](#)